



THK_ES5S6L-51S

Product introduction:

- Power supply: +5V DC
- Hall effect principle — open loop current sensor;
- The primary and secondary of the current sensor are insulated and can measure DC, AC, pulse, etc;

Application:

- Application on Inverter
- AC/DC variable speed drive
- Switching power supply (SMPS)
- UPS uninterruptible power supply
- Photovoltaic current detection application



Electrical characteristics:

Parameter	Symbol	THK15ES	THK20ES	THK25ES	THK50ES	THK100ES
		5S6L-51S	5S6L-51S	5S6L-51S	5S6L-51S	5S6L-51S
Rated current	$I_{PN}(A)$	15	20	25	50	100
Measuring range	$I_P(A)$	$0 \sim \pm 48$	$0 \sim \pm 64$	$0 \sim \pm 80$	$0 \sim \pm 160$	$0 \sim \pm 250$
Overload current	$I_{PM}(A)$	300				
Output voltage	$V_O(V)$	$2.5 \pm 0.625 * (I_P / I_{PN})$				
Offset voltage	$V_{OE}(mV)$	$< \pm 10$				
Working power supply	$V_C(V)$	$\pm 5V \text{ DC} \pm 5\%$				
Insulation voltage	$V_D(V)$	50/60Hz, 1min, 4kV; RMS				
Insulation impedance	$R_{IS}(M\Omega)$	500VDC, > 1000				

General parameters:

Project	Condition	Date	Unit
Accuracy X_G	@ $I_{PN}, T=25^\circ C$	$< \pm 1.0$	%
Voltage offset temperature drift V_{OT}	@ $I_P=0, -40 \sim +85^\circ C$	$< \pm 0.07$	mV/ $^\circ C$
Amplitude temperature drift V_{OS}	@ $I_P= I_{PN}, -40 \sim +85^\circ C$	$< \pm 2.0$	mV/ $^\circ C$
Linearity ϵ_r		≤ 0.5	%FS
Follow accuracy di/dt		> 50	A/ μs
Response time t_{ra}	@ 90% of I_{PN}	< 1.0	ms
Operating bandwidth B_w	-3dB	DC-50	KHZ
Working temperature T_A		$-40 \sim +125$	$^\circ C$
Storage temperature T_s		$-55 \sim +150$	$^\circ C$
Static power consumption I_c		12+Is	mA
Product weight m		12	g
Shell material	PBT material containing 30% glass fiber, flame retardant grade: UL94- V0;		
Standard	IEC60950-1:2001	EN50178:1998	SJ20790-2000

